
HIGH-BANDWIDTH DUAL SPDT DIFFERENTIAL SIGNAL SWITCH WITH INPUT LOGIC TRANSLATION

1 FEATURES

- High-Bandwidth Data Paths – Up to 800 MHz
- Specified Break-Before-Make Switching
- Control Inputs Reference to V_{IO}
- Low Charge Injection
- Excellent ON-State Resistance Matching
- Low Total Harmonic Distortion (THD)
- 2.3-V to 3.6-V Power Supply (V_+)
- 1.65-V to 1.95-V Logic Supply (V_{IO})
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
 - 4000-V Human-Body Model

(A114-B, Class II)

- 1000-V Charged-Device Model (C101)
- 200-V Machine Model (A115-A)

2 APPLICATIONS

- Cell Phones
- PDAs
- Portable Instrumentation
- Low-Voltage Differential Signal Routing
- Mobile Industry Processor Interface (MIPI) Signal Routing



Table 1. TERMINAL ASSIGNMENTS

	A	B	C	D
1	IN1	NO1	COM1	NC1
2	V _{IO}	GND	GND	V ₊
3	IN2	NO2	COM2	NC2

**YZT PACKAGE
(BOTTOM VIEW)**

	A	B	C	D
1	③	④	⑨	⑩
2	②	⑤	⑧	⑪
3	①	⑥	⑦	⑫

3 DESCRIPTION/ORDERING INFORMATION

The TS3DS26227 is a dual single-pole double-throw (SPDT) analog switch that is designed to operate from 2.3 V to 3.6 V. The device offers high-bandwidth data paths, and a break-before-make feature to prevent signal distortion during the transferring of a signal from one path to another. The device has excellent total harmonic distortion (THD) performance and consumes very low power. These features make this device suitable for portable applications.

The TS3DS26227 has a separate logic supply pin (V_{IO}) that operates from 1.65 V to 1.95 V. V_{IO} powers the control circuitry, which allows the TS3DS26227 to be controlled by 1.8-V signals.

Table 2. ORDERING INFORMATION

T _A	PACKAGE ^{(1) (2)}		ORDERABLE PART NUMBER	TOP-SIDE MARKING ⁽³⁾
–40°C to 85°C	NanoFree™ – WCSP (DSBGA) 0.23-mm Large Bump – YZT (Pb-free)	Tape and reel	TS3DS26227YZTR	

(1) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

(2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

(3) YZT: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, • = Pb-free).

Table 3. SUMMARY OF CHARACTERISTICS⁽¹⁾

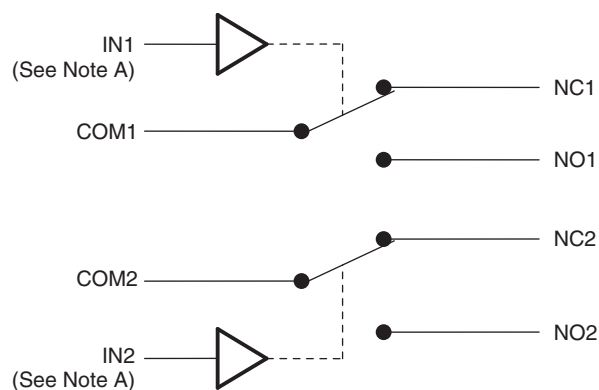
Configuration	Dual 2:1 Multiplexer/Demultiplexer (2 × SPDT)
Number of channels	2
ON-state resistance (r_{on})	5 Ω max
ON-state resistance match (Δr_{on})	0.1 Ω max
ON-state resistance flatness [$r_{on(Flat)}$]	3 Ω max
Turn-on/turn-off time (t_{ON}/t_{OFF})	9 ns/4 ns
Break-before-make time (t_{BBM})	8 ns
Charge injection (Q_C)	5.5 pC
Bandwidth (BW)	800 MHz
OFF isolation (O_{ISO})	–40 dB
Crosstalk (X_{TALK})	–39 dB
Leakage current [$I_{NO(OFF)}/I_{NC(OFF)}$]	± 5 nA
Power-supply current (I_+)	± 20 nA
Package options	12-bump WCSP

(1) $V_+ = 2.7$ V, $T_A = 25^\circ\text{C}$

Table 4. FUNCTION TABLE

IN	NC TO COM, COM TO NC	NO TO COM, COM TO NO
L	ON	OFF
H	OFF	ON

LOGIC DIAGRAM



A. IN1 and IN2 are control inputs referenced to V_{IO} .

3.1 ABSOLUTE MAXIMUM RATINGS^{(1) (2)}

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_+ V_{IO}	Supply voltage range ⁽³⁾		–0.5	4.6	V
V_{NC} V_{NO} V_{COM}	Analog voltage range ^{(3) (4) (5)}		–0.5	$V_+ + 0.5$	V
I_K	Analog port diode current	$V_{NC}, V_{NO}, V_{COM} < 0$, or $V_{NC}, V_{NO}, V_{COM} > V_+ + 0.5$	–50	50	mA
I_{NC} I_{NO} I_{COM}	On-state switch current	$V_{NC}, V_{NO}, V_{COM} = 0$ to V_+	–64	64	mA
	On-state peak switch current		–100	100	
V_I	Digital input voltage range		–0.5	$V_{IO} + 0.5$	V
I_{IK}	Digital input clamp current ^{(3) (4)}	$V_I < 0$, or $V_I > V_{IO} + 0.5$	–50	50	mA
I_+	Continuous current through V_+		–100	100	mA
I_{GND}	Continuous current through GND		–100	100	mA
θ_{JA}	Package thermal impedance ⁽⁶⁾	YZT package		TBD	°C/W
T_{stg}	Storage temperature range		–65	150	°C

- (1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.
- (2) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
- (3) All voltages are with respect to ground, unless otherwise specified.
- (4) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- (5) This value is limited to 5.5 V maximum.
- (6) The package thermal impedance is calculated in accordance with JESD 51-7.

3.2 ELECTRICAL CHARACTERISTICS FOR 3.3-V SUPPLY⁽¹⁾

 $V_+ = 2.7 \text{ V to } 3.6 \text{ V}$, $V_{IO} = 1.65 \text{ V to } 1.95 \text{ V}$, $T_A = -40^\circ\text{C to } 85^\circ\text{C}$ (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	T_A	V_+	MIN	TYP	MAX	UNIT
Analog Switch								
Analog signal range	V_{COM}, V_{NO}, V_{NC}				0		V_+	V
ON-state resistance	r_{on}	$0 \leq (V_{NO} \text{ or } V_{NC}) \leq 1.6$, $I_{COM} = -10 \text{ mA}$, Switch ON, See Figure 13	25°C Full	2.7 V	3.5		5 6	Ω
ON-state resistance match between channels	Δr_{on}	$V_{NO} \text{ or } V_{NC} = 1.6 \text{ V}$, $I_{COM} = -10 \text{ mA}$, Switch ON, See Figure 13	25°C Full	2.7 V	0.05		0.1 0.2	Ω
ON-state resistance flatness	$r_{on(Flat)}$	$0 \leq (V_{NO} \text{ or } V_{NC}) \leq 1.6 \text{ V}$, $I_{COM} = -10 \text{ mA}$, Switch ON, See Figure 13	25°C Full	2.7 V	2		3 4	Ω
NC, NO OFF leakage current	$I_{NO(OFF)}, I_{NC(OFF)}$	$V_{NO} \text{ or } V_{NC} = 0.3 \text{ V}$, $V_{COM} = 3 \text{ V}$, or $V_{NO} \text{ or } V_{NC} = 3 \text{ V}$, $V_{COM} = 0.3 \text{ V}$, Switch OFF, See Figure 14	25°C Full	3.6 V	-5 -15	0.1	5 15	nA
NC, NO ON leakage current	$I_{NO(ON)}, I_{NC(ON)}$	$V_{NO} \text{ or } V_{NC} = 0.3 \text{ V}$, $V_{COM} = \text{Open}$, or $V_{NO} \text{ or } V_{NC} = 3 \text{ V}$, $V_{COM} = \text{Open}$, Switch ON, See Figure 15	25°C Full	3.6 V	-10 -30	0.2	10 30	nA
COM ON leakage current	$I_{COM(ON)}$	$V_{NO} \text{ or } V_{NC} = \text{Open}$, $V_{COM} = 0.3 \text{ V}$, or $V_{NO} \text{ or } V_{NC} = \text{Open}$, $V_{COM} = 3 \text{ V}$, Switch ON, See Figure 15	25°C Full	3.6 V	-10 -30	0.2	10 30	nA
Digital Control Inputs (IN1, IN2)⁽²⁾								
Input logic high	V_{IH}	$V_{IO} = 1.65 \text{ V to } 1.95 \text{ V}$	Full		$0.65 \times V_{IO}$		V_{IO}	V
Input logic low	V_{IL}	$V_{IO} = 1.65 \text{ V to } 1.95 \text{ V}$	Full		0		$0.35 \times V_{IO}$	V
Input leakage current	I_{IH}, I_{IL}	$V_{IN} = V_{IO} \text{ or } 0$	25°C Full	3.6 V	-2 -10	0.1	2 10	nA

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

(2) All unused digital inputs of the device must be held at V_{IO} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

ELECTRICAL CHARACTERISTICS FOR 3.3-V SUPPLY⁽¹⁾ (continued)
 $V_+ = 2.7\text{ V to }3.6\text{ V}$, $V_{IO} = 1.65\text{ V to }1.95\text{ V}$, $T_A = -40^\circ\text{C to }85^\circ\text{C}$ (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		T _A	V ₊	MIN	TYP	MAX	UNIT
Dynamic									
Turn-on time	t _{ON}	V _{COM} = V ₊ , R _L = 50 Ω,	C _L = 35 pF, See Figure 17	25°C	3.3 V	1	6.5	9	ns
				Full	2.7 to 3.6 V	1		11.5	
Turn-off time	t _{OFF}	V _{COM} = V ₊ , R _L = 50 Ω,	C _L = 35 pF See Figure 17	25°C	3.3 V	1	2	4	ns
				Full	2.7 to 3.6 V	1		5	
Break-before-make time	t _{BBM}	V _{NC} = V _{NO} = 0.6 V, R _L = 50 Ω,	C _L = 35 pF See Figure 18	25°C	3.3 V	0.5	4	8	ns
				Full	2.7 to 3.6 V	0.5		9	
Charge injection	Q _C	V _{GEN} = 0, R _{GEN} = 0,	C _L = 1 nF See Figure 22	25°C	3.3 V		5.5		pC
NC, NO OFF capacitance	C _{NC(OFF)} , C _{NO(OFF)}	V _{NC} or V _{NO} = 1.3 V or GND, Switch OFF,	See Figure 16	25°C	3.3 V		3.5		pF
NC, NO ON capacitance	C _{NC(ON)} , C _{NO(ON)}	V _{NC} or V _{NO} = 1.3 V or GND, Switch ON,	See Figure 16	25°C	3.3 V		10.5		pF
COM ON capacitance	C _{COM(ON)}	V _{COM} = 1.3 V or GND, Switch ON,	See Figure 16	25°C	3.3 V		10.5		pF
Digital input capacitance	C _I	V _I = V ₊ or GND	See Figure 16	25°C	3.3 V		2		pF
Bandwidth	BW	R _L = 50 Ω,	Switch ON See Figure 19	25°C	2.7 V		800		MHz
OFF isolation	O _{ISO}	R _L = 50 Ω, f = 200 MHz,	Switch OFF See Figure 20	25°C	2.7 V		−40		dB
Crosstalk	X _{TALK}	R _L = 50 Ω, f = 200 MHz,	Switch ON See Figure 21	25°C	2.7 V		−39		dB
Supply									
Positive supply current	I ₊	V _I = V ₊ or GND,	Switch ON or OFF	25°C	3.6 V	−20	1	20	nA
				Full		−500		500	
Logic supply current	I _{IO}	V _I = V _{IO} or GND,	Switch ON or OFF	25°C	3.6 V	−10	1	10	nA
				Full		−200		200	

3.3 ELECTRICAL CHARACTERISTICS FOR 2.5-V SUPPLY⁽¹⁾

 $V_+ = 2.3 \text{ V to } 2.7 \text{ V}$, $V_{IO} = 1.65 \text{ V to } 1.95 \text{ V}$, $T_A = -40^\circ\text{C to } 85^\circ\text{C}$ (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	T_A	V_+	MIN	TYP	MAX	UNIT
Analog Switch								
Analog signal range	V_{COM}, V_{NO}, V_{NC}				0		V_+	V
ON-state resistance	r_{on}	$0 \leq (V_{NO} \text{ or } V_{NC}) \leq 1.3$, $I_{COM} = -10 \text{ mA}$, Switch ON, See Figure 13	25°C	2.3 V		4	5.5	Ω
			Full				7	
ON-state resistance match between channels	Δr_{on}	$V_{NO} \text{ or } V_{NC} = 1.3 \text{ V}$, $I_{COM} = -10 \text{ mA}$, Switch ON, See Figure 13	25°C	2.3 V		0.05	0.1	Ω
			Full				0.2	
ON-state resistance flatness	$r_{on(flat)}$	$0 \leq (V_{NO} \text{ or } V_{NC}) \leq 1.3 \text{ V}$, $I_{COM} = -10 \text{ mA}$, Switch ON, See Figure 13	25°C	2.3 V		2.5	4	Ω
			Full				4.5	
NC, NO OFF leakage current	$I_{NO(OFF)}, I_{NC(OFF)}$	$V_{NO} \text{ or } V_{NC} = 0.2 \text{ V}$, $V_{COM} = 2.3 \text{ V}$, or $V_{NO} \text{ or } V_{NC} = 2.3 \text{ V}$, $V_{COM} = 0.2 \text{ V}$, Switch OFF, See Figure 14	25°C	2.7 V	-5	0.1	5	nA
			Full		-15		15	
NC, NO ON leakage current	$I_{NO(ON)}, I_{NC(ON)}$	$V_{NO} \text{ or } V_{NC} = 0.2 \text{ V}$, $V_{COM} = \text{Open}$, or $V_{NO} \text{ or } V_{NC} = 2.3 \text{ V}$, $V_{COM} = \text{Open}$, Switch ON, See Figure 15	25°C	2.7 V	-5	0.2	5	nA
			Full		-20		20	
COM ON leakage current	$I_{COM(ON)}$	$V_{NO} \text{ or } V_{NC} = \text{Open}$, $V_{COM} = 0.2 \text{ V}$, or $V_{NO} \text{ or } V_{NC} = \text{Open}$, $V_{COM} = 2.3 \text{ V}$, Switch ON, See Figure 15	25°C	2.7 V	-1	0.05	1	nA
			Full		-10		10	
Digital Control Inputs (IN1, IN2)⁽²⁾								
Input logic high	V_{IH}	$V_{IO} = 1.65 \text{ V to } 1.95 \text{ V}$	Full		$0.65 \times V_{IO}$		V_{IO}	V
Input logic low	V_{IL}	$V_{IO} = 1.65 \text{ V to } 1.95 \text{ V}$	Full		0		$0.35 \times V_{IO}$	V
Input leakage current	I_{IH}, I_{IL}	$V_{IN} = V_{IO} \text{ or } 0$	25°C	2.7 V	-1	0.05	1	nA
			Full		-10		10	

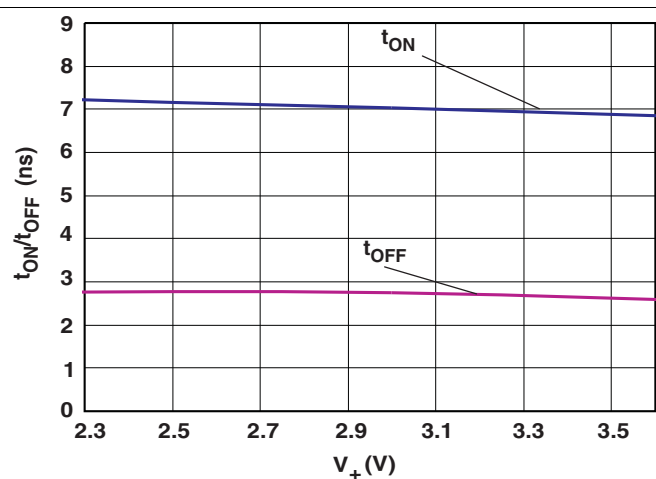
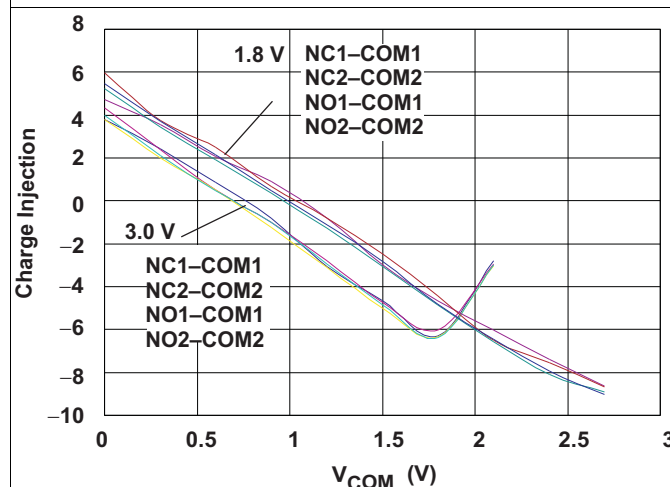
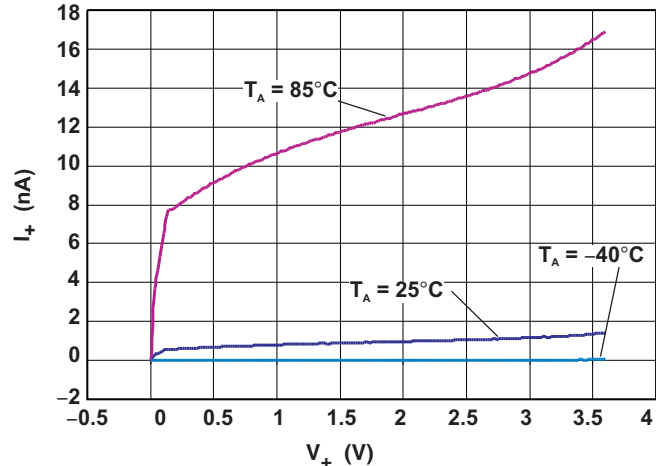
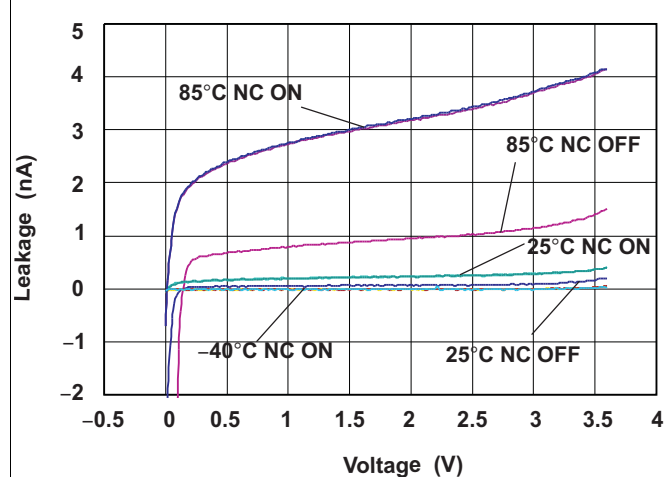
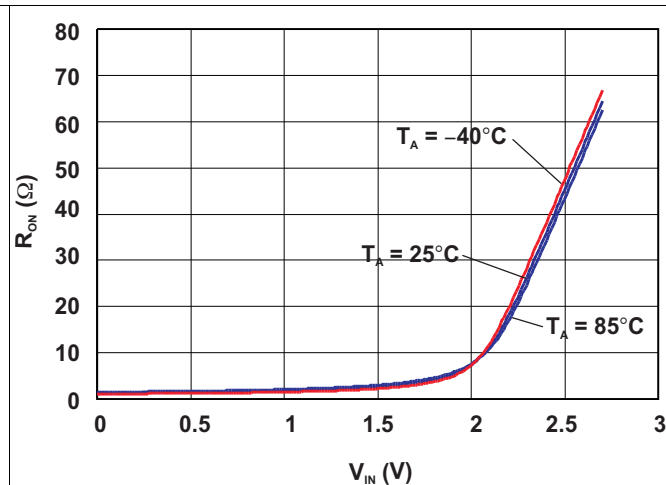
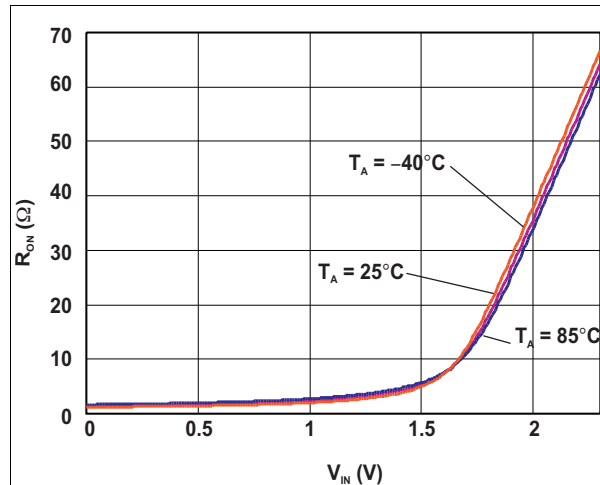
(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

(2) All unused digital inputs of the device must be held at V_{IO} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

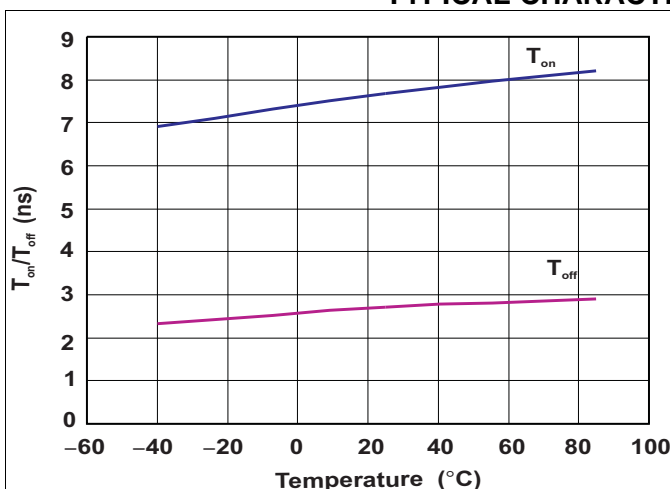
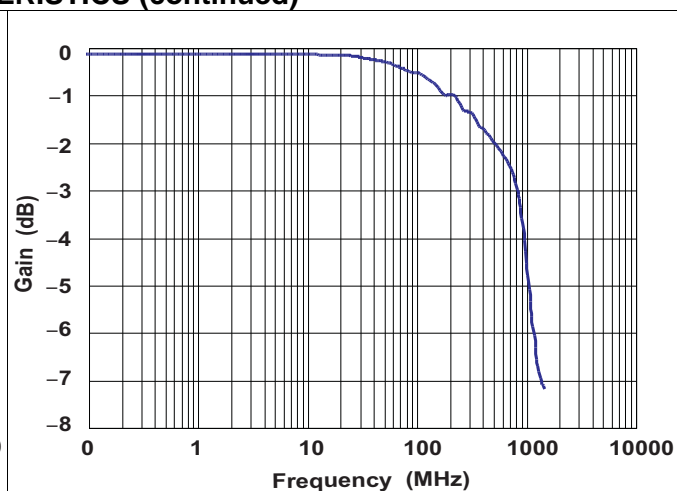
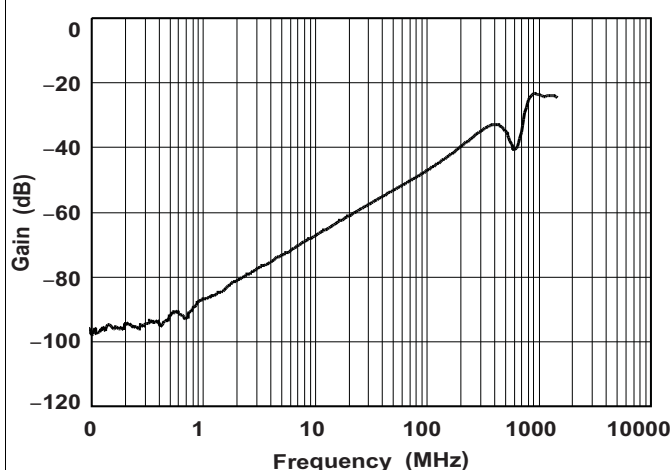
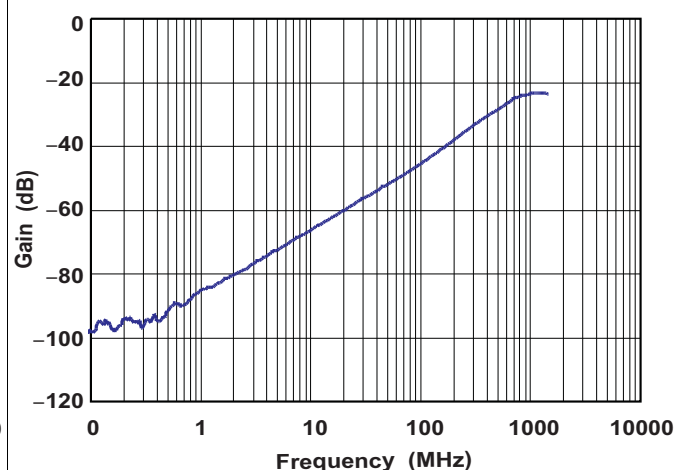
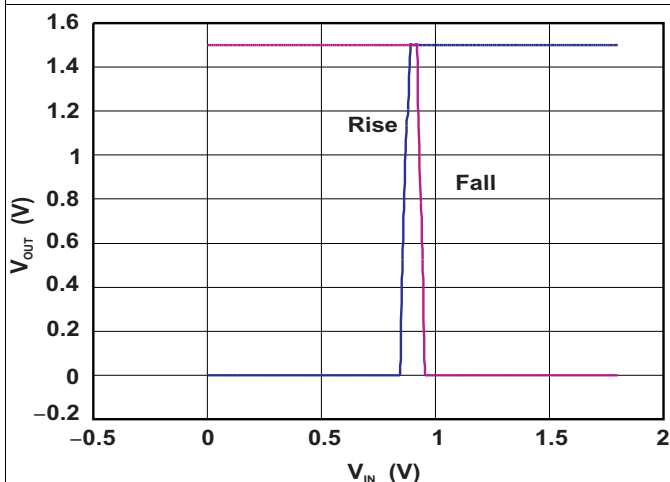
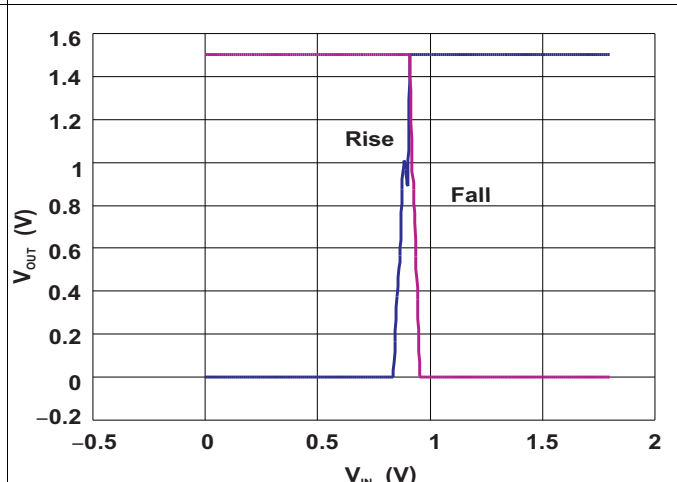
ELECTRICAL CHARACTERISTICS FOR 2.5-V SUPPLY⁽¹⁾ (continued)
 $V_+ = 2.3 \text{ V to } 2.7 \text{ V}$, $V_{IO} = 1.65 \text{ V to } 1.95 \text{ V}$, $T_A = -40^\circ\text{C to } 85^\circ\text{C}$ (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	T_A	V_+	MIN	TYP	MAX	UNIT
Dynamic								
Turn-on time	t_{ON}	$V_{COM} = V_+$, $R_L = 50 \Omega$, $C_L = 35 \text{ pF}$ See Figure 17	25°C	2.5 V	1	7	11	ns
			Full	2.3 to 2.7 V	1		13	
Turn-off time	t_{OFF}	$V_{COM} = V_+$, $R_L = 50 \Omega$, $C_L = 35 \text{ pF}$ See Figure 17	25°C	2.5 V	1	2.5	4.5	ns
			Full	2.3 to 2.7 V	1		5.5	
Break-before-make time	t_{BBM}	$V_{NC} = V_{NO} = 0.6 \text{ V}$, $R_L = 50 \Omega$, $C_L = 35 \text{ pF}$ See Figure 18	25°C	2.3 V	1	4	8	ns
			Full	2.3 to 2.7 V	1		10	
Charge injection	Q_C	$V_{GEN} = 0$, $R_{GEN} = 0$, $C_L = 1 \text{ nF}$ See Figure 22	25°C	2.5 V		4		pC
NC, NO OFF capacitance	$C_{NC(OFF)}$, $C_{NO(OFF)}$	V_{NC} or $V_{NO} = 1.6 \text{ V}$ or GND, Switch OFF, See Figure 16	25°C	2.5 V		3.5		pF
NC, NO ON capacitance	$C_{NC(ON)}$, $C_{NO(ON)}$	V_{NC} or $V_{NO} = 1.6 \text{ V}$ or GND, Switch ON, See Figure 16	25°C	2.5 V		10.5		pF
COM ON capacitance	$C_{COM(ON)}$	$V_{COM} = 1.6 \text{ V}$ or GND, Switch ON, See Figure 16	25°C	2.5 V		10.5		pF
Digital input capacitance	C_I	$V_I = V_+$ or GND See Figure 16	25°C	2.5 V		2		pF
Bandwidth	BW	$R_L = 50 \Omega$, Switch ON See Figure 19	25°C	2.3 V		800		MHz
OFF isolation	O_{ISO}	$R_L = 50 \Omega$, $f = 200 \text{ MHz}$, Switch OFF See Figure 20	25°C	2.3 V		-40		dB
Crosstalk	X_{TALK}	$R_L = 50 \Omega$, $f = 200 \text{ MHz}$, Switch ON See Figure 21	25°C	2.3 V		-39		dB
Supply								
Positive supply current	I_+	$V_I = V_+$ or GND, Switch ON or OFF	25°C	2.7 V	-10	1	10	nA
			Full		-350		350	
Logic supply current	I_{IO}	$V_I = V_{IO}$ or GND, Switch ON or OFF	25°C	2.7 V	-5	1	5	nA
			Full		-200		200	

4 TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS (continued)

Figure 7. t_{on}/t_{off} vs Temperature, $V_+ = 2.3 \text{ V}$ Figure 8. Bandwidth, $V_+ = 2.5 \text{ V}$ Figure 9. OFF Isolation vs Frequency, $V_+ = 2.5 \text{ V}$ Figure 10. Crosstalk vs Frequency, $V_+ = 2.5 \text{ V}$ Figure 11. Threshold Voltage, $V_{IO} = 1.8 \text{ V}$, $V_+ = 2.7 \text{ V}$ Figure 12. Threshold Voltage, $V_{IO} = 1.8 \text{ V}$, $V_+ = 3.6 \text{ V}$

5 PARAMETER MEASUREMENT INFORMATION

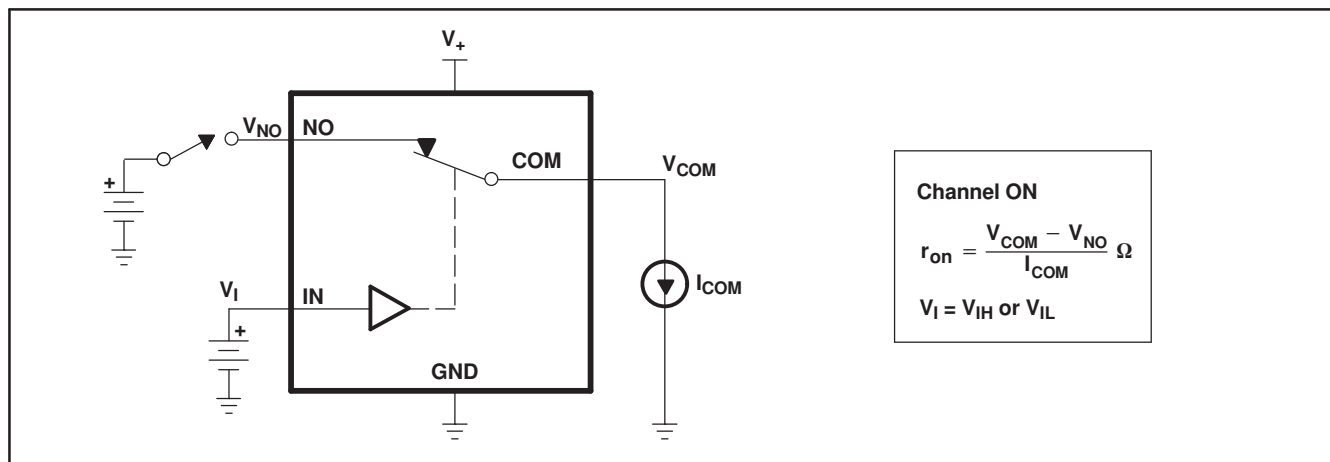


Figure 13. ON-State Resistance (r_{on})

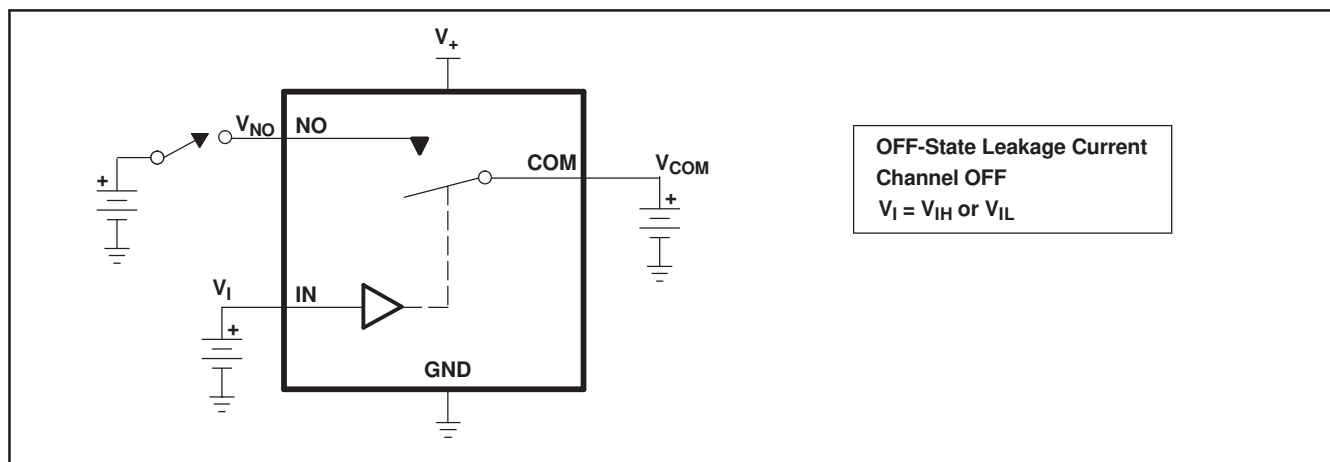


Figure 14. OFF-State Leakage Current ($I_{COM(OFF)}$, $I_{NC(OFF)}$, $I_{COM(PWROFF)}$, $I_{NC(PWROFF)}$)

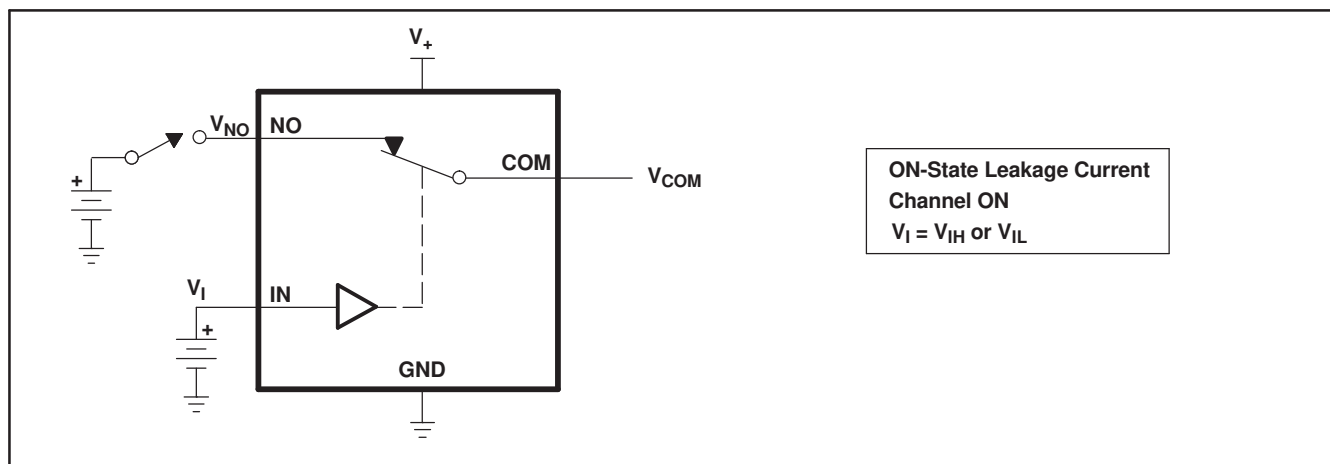


Figure 15. ON-State Leakage Current ($I_{COM(ON)}$, $I_{NC(ON)}$)

PARAMETER MEASUREMENT INFORMATION (continued)

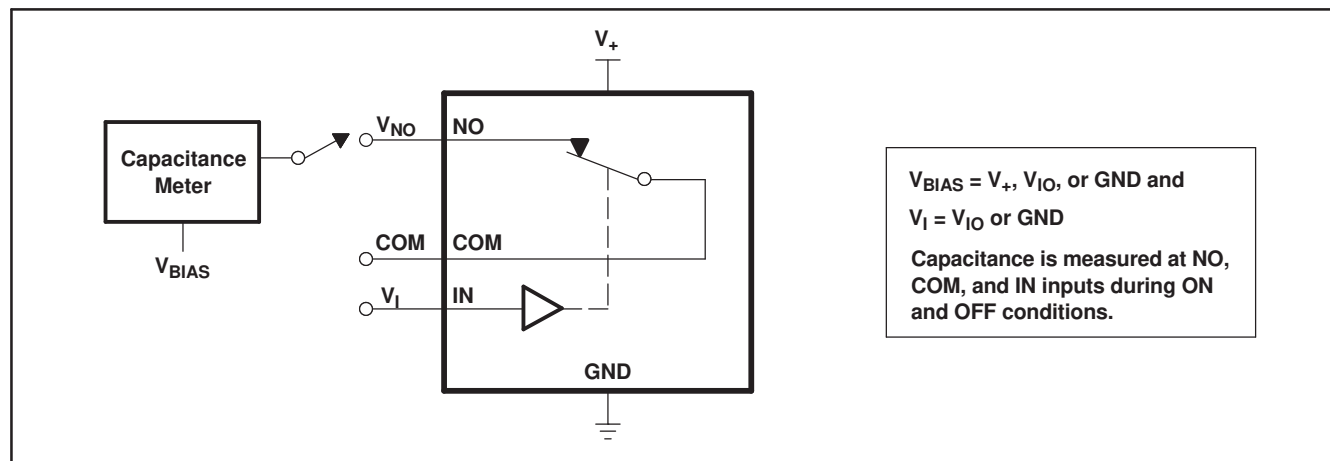
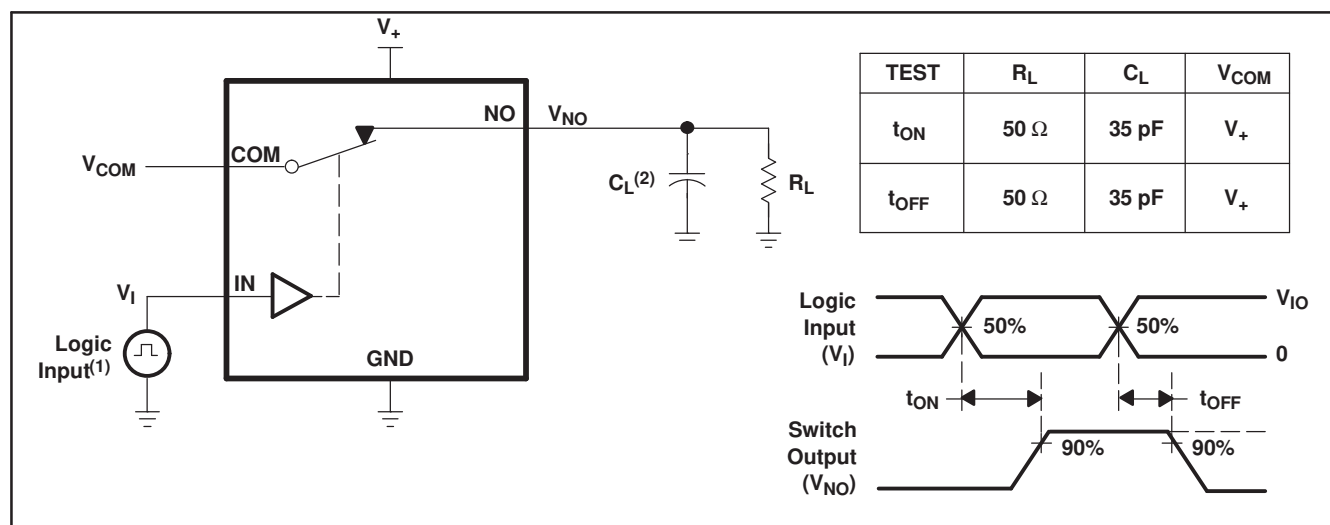


Figure 16. Capacitance (C_I , $C_{COM(OFF)}$, $C_{COM(ON)}$, $C_{NC(OFF)}$, $C_{NC(ON)}$)

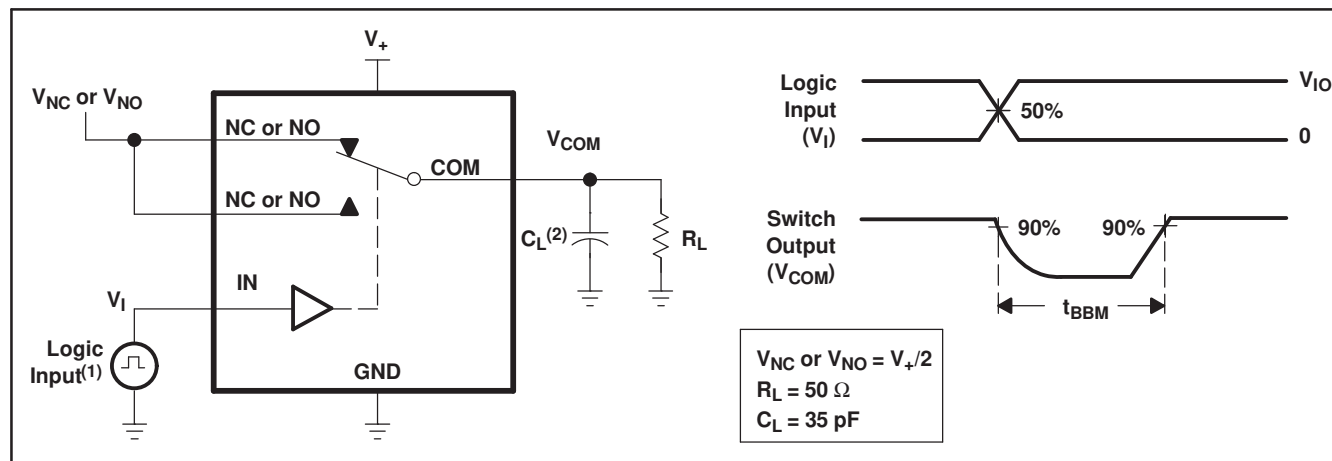


(1) All input pulses are supplied by generators having the following characteristics: $PRR \leq 10\ \text{MHz}$, $Z_O = 50\ \Omega$, $t_r < 5\ \text{ns}$, $t_f < 5\ \text{ns}$.

(2) C_L includes probe and jig capacitance.

Figure 17. Turn-On (t_{ON}) and Turn-Off Time (t_{OFF})

PARAMETER MEASUREMENT INFORMATION (continued)



(1) All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, $Z_O = 50 \Omega$, $t_r < 5$ ns, $t_f < 5$ ns.

(2) C_L includes probe and jig capacitance.

Figure 18. Break-Before-Make Time (t_{BBM})

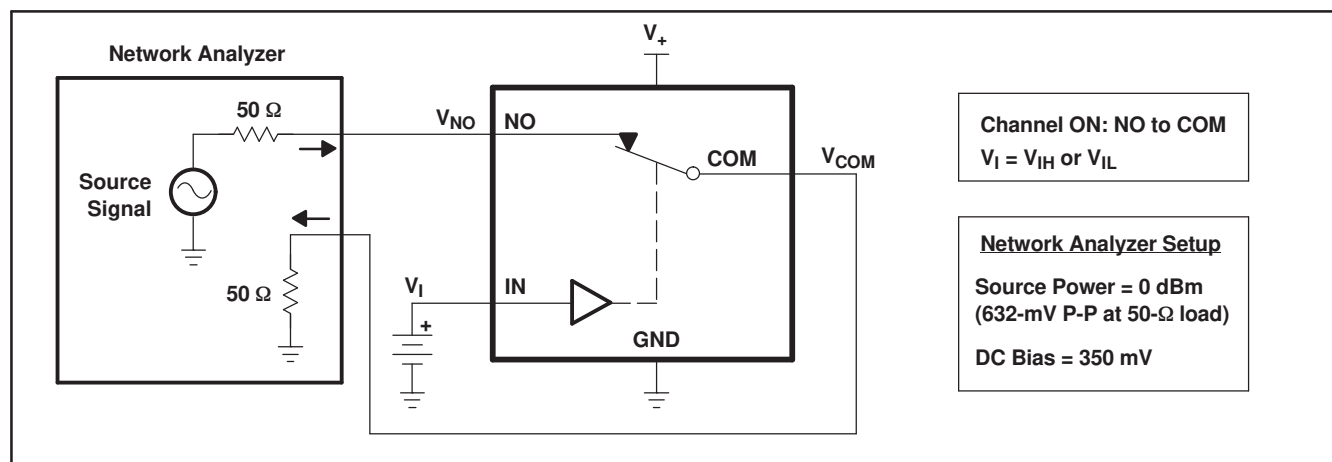


Figure 19. Bandwidth (BW)

PARAMETER MEASUREMENT INFORMATION (continued)

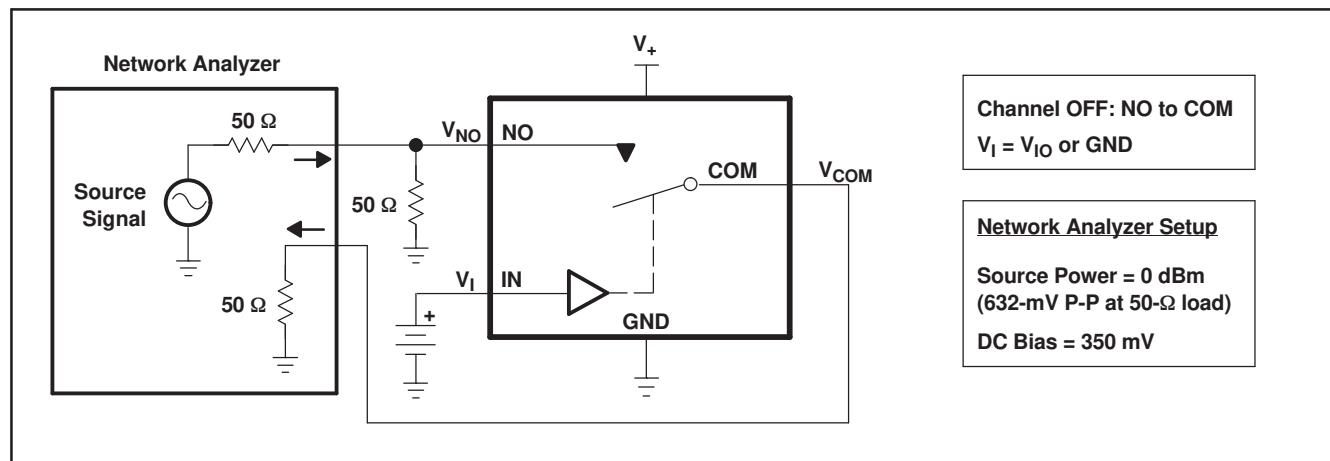


Figure 20. OFF Isolation (O_{ISO})

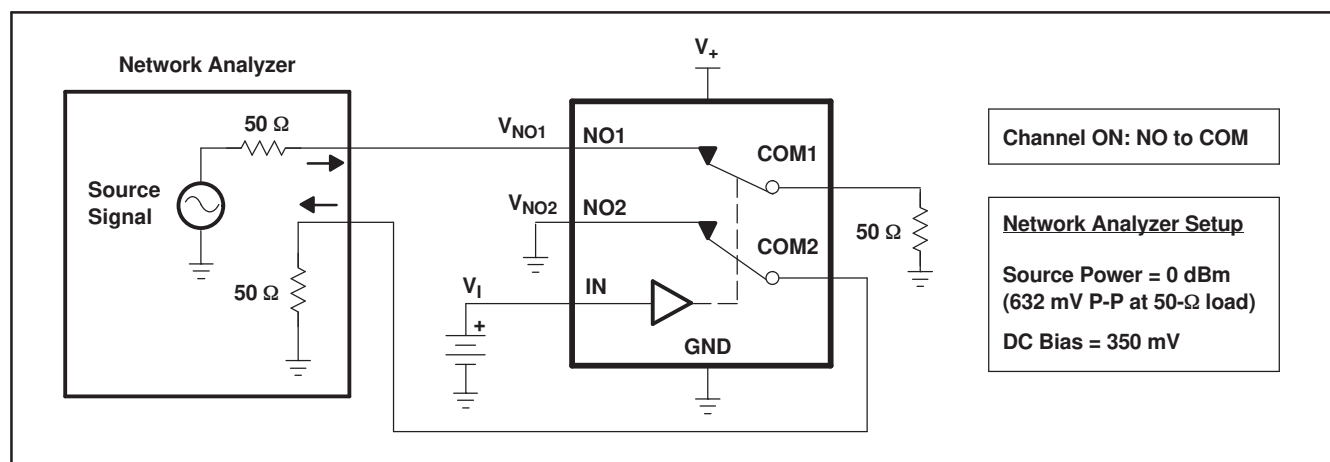
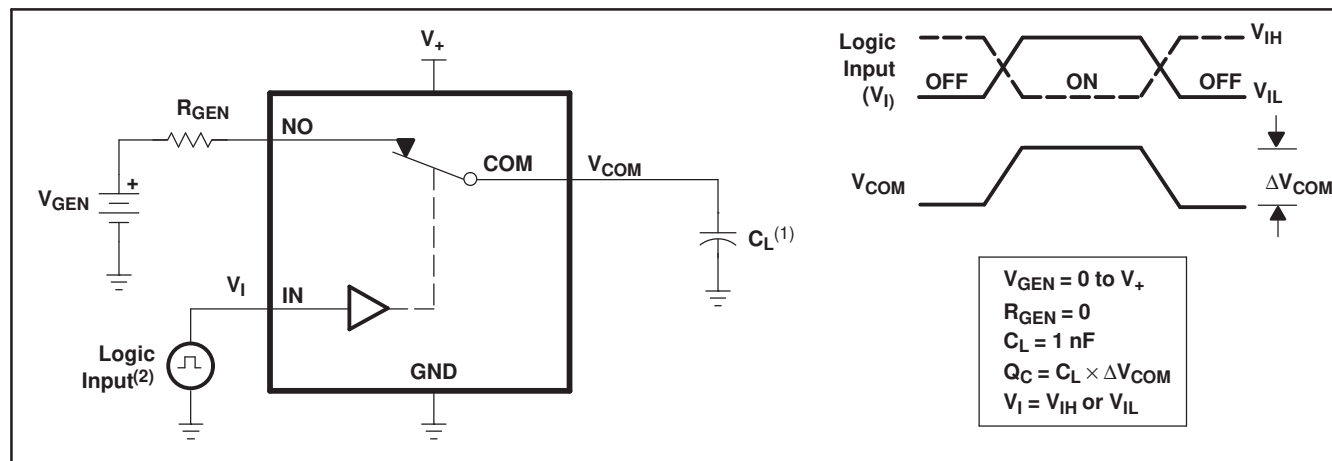


Figure 21. Crosstalk (X_{TALK})

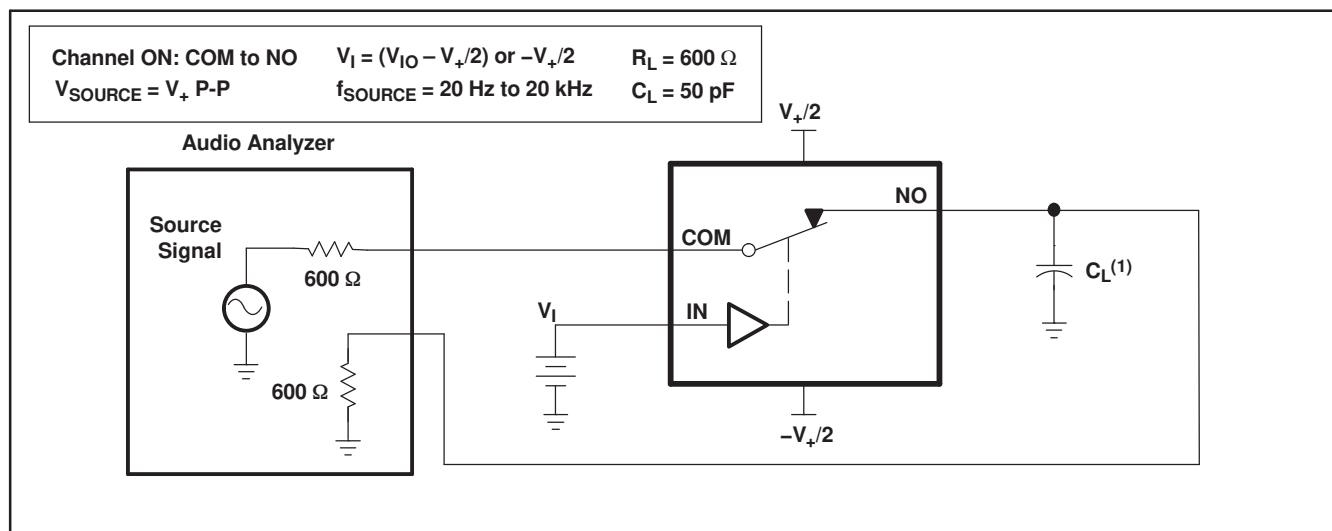
PARAMETER MEASUREMENT INFORMATION (continued)



(1) C_L includes probe and jig capacitance.

(2) All input pulses are supplied by generators having the following characteristics: $PRR \leq 10 \text{ MHz}$, $Z_O = 50 \Omega$, $t_r < 5 \text{ ns}$, $t_f < 5 \text{ ns}$.

Figure 22. Charge Injection (Q_C)



(1) C_L includes probe and jig capacitance.

Figure 23. Total Harmonic Distortion (THD)

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TS3DS26227YZTR	Active	Production	DSBGA (YZT) 12	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	(262, 26N)
TS3DS26227YZTR.B	Active	Production	DSBGA (YZT) 12	3000 LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	(262, 26N)

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TS3DS26227YZTR	DSBGA	YZT	12	3000	178.0	9.2	1.49	1.99	0.75	4.0	8.0	Q2

TAPE AND REEL BOX DIMENSIONS



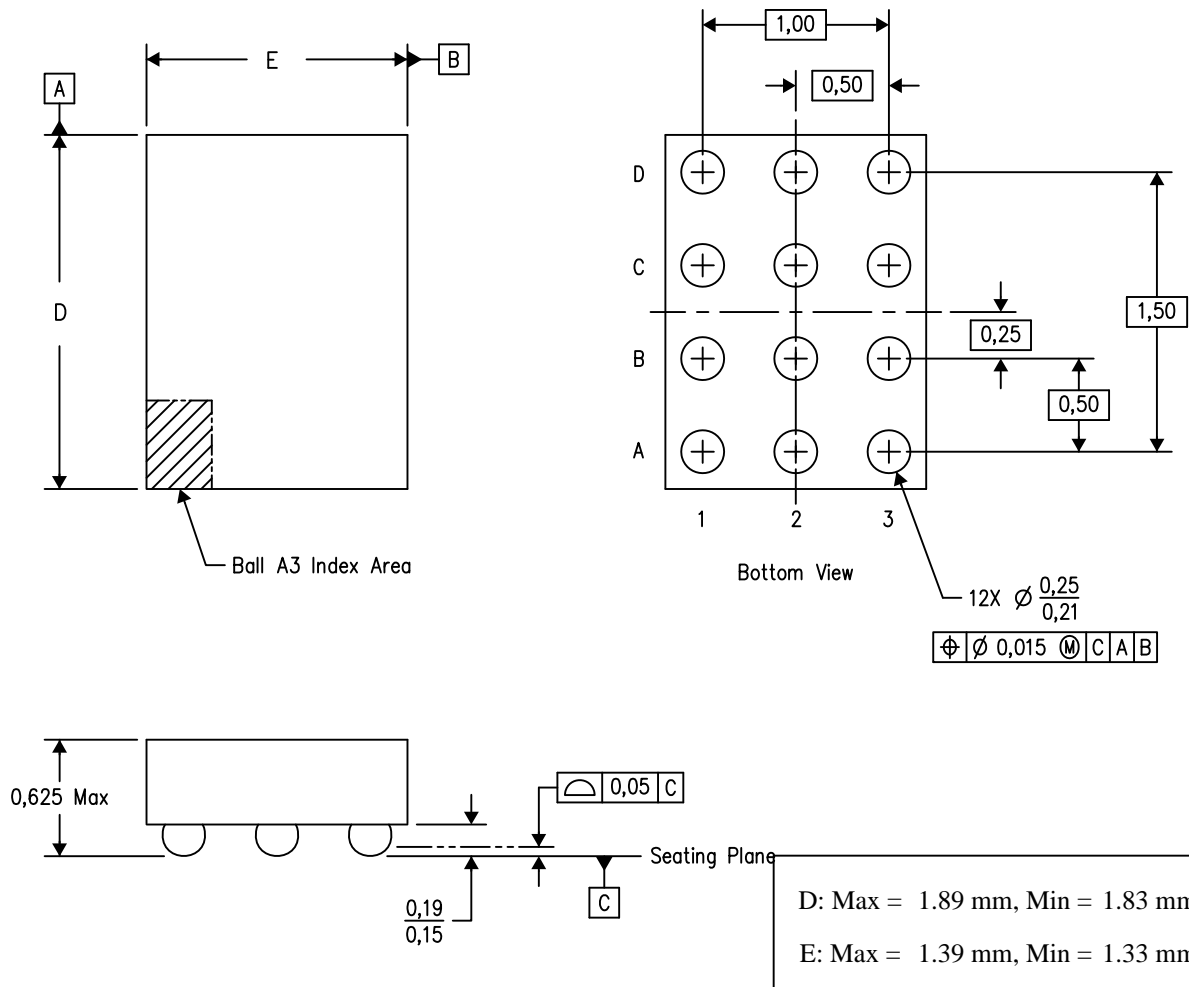
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TS3DS26227YZTR	DSBGA	YZT	12	3000	220.0	220.0	35.0

MECHANICAL DATA

YZT (R-XBGA-N12)

(CUSTOM) DIE-SIZE BALL GRID ARRAY



4205418-6/H 05/13

- NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
B. This drawing is subject to change without notice.
C. NanoFree™ package configuration.

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